Datasheet



QL85F6SA/B/C

- 850nm 10mW 60 $^\circ\mathrm{C}$
- Infrared Laser

Feb. 2019 (Ver. 2)

- Application
- Industrial Optical Sensor

• Features

- 850nm Infrared Laser
- CW laser (Continuous Wave)
- Single Transvers / TE mode laser
- 5.6mm Package

• Electrical Connection

P/N	Pin Configuration	Internal Circuit		
QL85F6SA/B/C	Bottom View	3.PD 3.PD 1.LD 3.PD 1.LD 1.LD		
		2.COMMON A type 2.COMMON B type 3.PD 1.LD 2.COMMON C type		



1. ABSOLUTE MAXIMUM RATING

Item	Symbols	Values	Unit
Optical Output Power	Р	10	mW
Laser Diode Reverse Voltage	V	2	V
Photo Diode Reverse Voltage	V	30	V
Operating Temperature	$\mathrm{T}_{\mathrm{opr}}$	-10 ~ +60	°C
Storage Temperature	$\mathrm{T}_{\mathrm{stg}}$	-40 ~ +85	°C

2. ELECTRICAL and OPTICAL CHARACTERISTICS at Tc=25 $^\circ\text{C}$

Item	Symbol	Min	Тур	Max	Unit	Condition
Threshold Current	I _{th}	5	10	20	mA	-
Operating Current	I _{op}	15	25	35	mA	Po=10mW
Operating Voltage	V _{op}	-	1.9	2.5	V	Po=10mW
Slope Efficiency	η _s	0.4	0.7	0.9	mW/mA	5mW/ (I(10mW)-I(5mW))
Lasing Wavelength	λ_{p}	845	850	855	nm	Po=10mW
Beam Divergence	θ_{II}	7	9	12	deg	Po=10mW FWHM
	θ_{\perp}	25	32	40	deg	
Beam Angle	$\Delta \theta_{\mathrm{II}}$	-2	-	+2	deg	Po=10mW
	$\Delta heta_{\perp}$	-3	-	+3	deg	Po=10mW
Monitor Current	I _m	0.1	0.3	0.5	deg	Po=10mW
Optical Distance	ΔΧ, ΔΥ, ΔΖ	-60	-	+60	μm	-

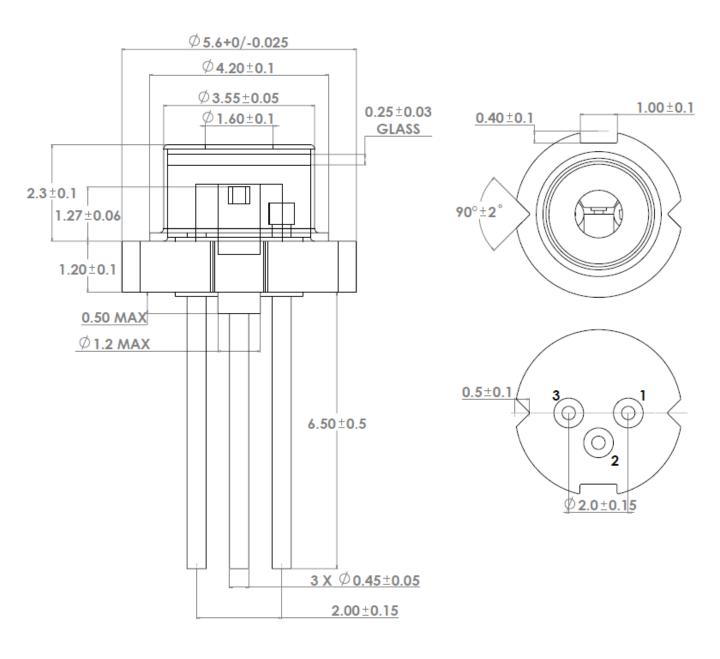
Note : Tc = Case (Stem) temperature

- Use in APC condition with heat sink and do not exceed 10mW 60 $^\circ \! \mathbb{C}$

- The products and product specifications are subject to change without notice.



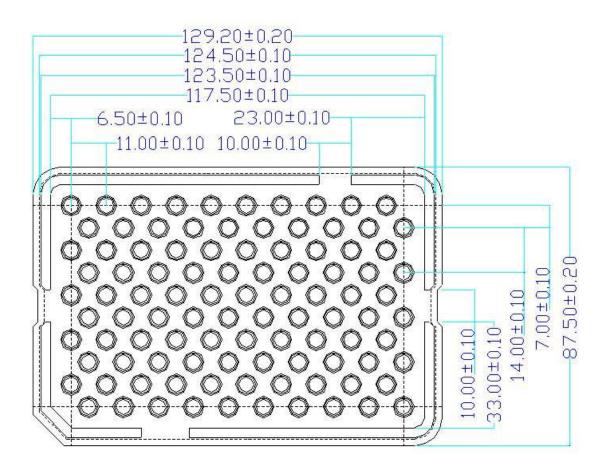
3. PACKAGE DIMENSION (unit : mm)

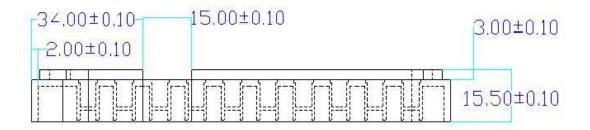


Note : Tolerance is $\pm 0.05 \text{mm}$ for items without tolerance marking



4. PACKING







5. PRECAUTIONS

1) Absolute maximum ratings

The absolute maximum ratings which must not be exceeded even momentarily have been established for over driving laser operation reason such as COD. Exercise particular caution with respect to the drive voltage supply and static electricity.

2) Prevention of surge current and electrostatic discharge(ESD) and surge stress

Laser diode is sensitive device to ESD and surge, so even an extremely short time, laser diode damaged with the strong light emitted.

Use the power supply that was designed not to exceed the optical power output specified at the absolute maximum ratings

We advise talking the following protective measures

- -. Ground the device and circuits
- -. When working with laser diodes wear anti-static clothing. Grounded wrist straps should always be worn while working with laser diodes.
- -. Use anti-static containers for transport and storage.
- -. Laser diode deterioration and damage can occur due to excessive current spikes when the power is turned on or off.
 - Design circuits to avoid the generating of excessive current spikes

3) Soldering

When soldering, please give attention to the mechanical stress and the temperature. Temperature of die-pad portion should be less than 200°C. It is recommended to radiate heat by putting heat sink on the package. X Soldering temperature and time : Iron temperature less than 350°C within3sec (leads only)

4) Eye Safety

When the laser diode is in operation, looking into laser beam directly by naked eyes, even through a lens, microscope or optical fibers, may cause severe damage to human eyes. For observing laser beams, using safety goggles is recommended